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November 2014

## FSA550 4PST Depletion Mode Isolation Switch

#### **Features**

- 4PST (NC)
- Depletion Mode MOSFETs
- Audio Frequency Range
- V<sub>CC(OFF)</sub>: 1.6 V to 3.0 V
- R<sub>ON</sub>: 0.8 Ω Typical
- R<sub>ON</sub> Flat: 0.01 Ω Typical
- THD+N: 0.002% Typical
- Eco Status: Fairchild Green, RoHS Compliant, Halogen Free

## **Applications**

- MP3 Portable Media Players
- Cellular Phones, Smart Phones

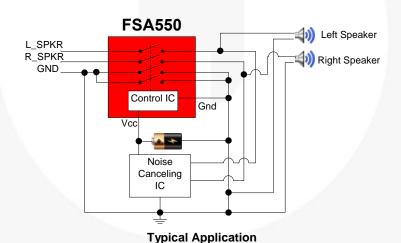
### Description

The FSA550 is a high-performance four-pole single-throw (4PST) normally closed Depletion-Mode isolation switch. The Depletion Mode technology allows the device to conduct signals when there is no  $V_{\rm CC}$  available and to isolate the signals when  $V_{\rm CC}$  is present.

The FSA550 operates on a wide  $V_{CC}$  range for design flexibility. Additionally, select pins allow the internal oscillator frequency to be adjusted between 500 kHz and 750 kHz in 75 kHz steps when  $V_{CC}$  is present. This feature is used to shift the electromagnetic interference (EMI) signature to meet customer specifications.

#### **Related Resources**

FSA550 Evaluation Board



#### **Ordering Information**

Part Number	FSA550UCX M4 -40 to +85°C		Package	Packing Method
FSA550UCX			12-Ball WLCSP, 3 x 4 Array, 0.4 mm Pitch, 250 µm Ball	3000 Units on Tape and Reel
		-40 to +85°C	12-Ball WLCSP(with Backside Laminate), 3 x 4 Array, 0.4 mm Pitch, 250 µm Ball	3000 Units on Tape and Reel

## Pin Configuration

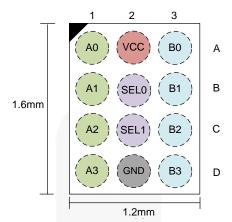


Figure 1. Pin Assignment (Top Through View)

## **Pin Descriptions**

Pin#	Name	Туре	Description		
A1	A0	I/O	A - Port		
B1	A1	I/O	A - Port		
C1	A2	I/O	A - Port		
D1	А3	I/O	A - Port		
A2	Vcc	Supply / Control	solation Circuit Supply Voltage (see Table 1)		
B2	SEL0	Input	Oscillator Frequency Control (see Table 2). Used to shift the electromagnetic		
C2	SEL1	Input	interference (EMI) signature to meet the customer specifications.		
D2	GND	Ground	System Ground		
А3	В0	I/O	B - Port		
В3	B1	I/O	B - Port		
C3	B2	I/O	B - Port		
D3	В3	I/O	B - Port		

Table 1. Truth Table

V <sub>cc</sub>	Function
0 V – 0.2 V	B0-B3 = A0-A3
1.6 V - 3.0 V	Disconnect; B0-B3 ≠ A0-A3

Table 2. Oscillator Frequency Step Logic

SEL1	SEL0	Frequency (Typ.)
LOW	LOW	500 kHz
LOW	HIGH	575 kHz
HIGH	LOW	650 kHz
HIGH	HIGH	725 kHz

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
V <sub>CC</sub>	Supply/Control Voltage		0	4.6	V
V <sub>IN</sub>	Input Voltage (Select Pins)		0	Vcc	V
V <sub>SW(ON)</sub>	DC Switch I/O Voltage (Switch Conducting)	V <sub>CC</sub> =0 V	-4	+4	V
V <sub>SW(OFF)</sub> <sup>(1)</sup>	DC Switch I/O Voltage (Switch Isolated)	V <sub>CC</sub> =Powered	-0.5	3.0	V
I <sub>IK</sub>	DC Input Diode Current		-50		mA
I <sub>SW</sub>	Switch I/O Current	V <sub>CC</sub> =0 V (Switch Conducting)		350	mA
I <sub>SWPEAK</sub>	Peak Switch Current	Pulsed at 1 ms Duration, <10% Duty Cycle		500	mA
	Human Body Model, ANSI/ESDA/JEDEC JS-001-2012	Oly/Control Voltage   O   4.6	5.0		
ESD	Charged Device Model, JEDEC: JESD22-C1			1.5	kV
	IFC 64000 4 2 System	Contact		8.0	
	IEC 01000-4-2 System	Air Gap	0 4.6 0 V <sub>CC</sub> -4 +4 1 -0.5 3.0 -50 tch Conducting) 350 is Duration, ycle 5.0 1.5 8.0 15.0 -40 +85		
T <sub>A</sub>	Absolute Maximum Operating Temperature		-40	+85	°C
T <sub>STG</sub>	Storage Temperature		-65	+150	°C

#### Note:

1. When a switch is isolated (OFF), V<sub>SW</sub> value must be < V<sub>CC</sub>.

## **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	7	Min.	Max.	Unit
V <sub>CC(ON)</sub>	Supply Voltage with Switch Conducting		0	0.2	V
V <sub>CC (OFF)</sub>	Supply Voltage with Switch Isolated	Supply Voltage with Switch Isolated		3.0	V
V <sub>SW(ON)</sub>	DC Switch I/O Voltage (Switch Conducting)	V <sub>CC</sub> = 0 V	-2	2	V
V <sub>SW(OFF)</sub>	DC Switch I/O Voltage (Switch Isolated)	V <sub>CC</sub> = 1.6 V to 3.0 V	0	1.4	V

#### **DC Electrical Characteristics**

Typical values at  $T_A = 25$ °C unless otherwise specified.

Symbol	Parameter	Condition	V <sub>cc</sub> (V)	T <sub>A</sub> =- 40°C to +85°C			Unit
Cymbol	T di diffetei	Condition	• 66 (•)	Min.	Тур.	Max.	
I <sub>ON</sub>	Switch-to-GND Leakage Current (Switch Conducting)	$A_n = -1.4 \text{ V to } 1.4 \text{ V},$ $B_n = \text{Float}$	0	0	0.3	1.0	μΑ
I <sub>OFF</sub>	Switch-to-GND Leakage Current (Switch Isolated)	$A_n = 0.4 \text{ V to } 1.4 \text{ V},$ $B_n = \text{Float}$	3	0	0.5	3.5	μΑ
R <sub>ON</sub>	Switch On Resistance <sup>(2)</sup>	$I_{SW} = \pm 24 \text{ mA},$ $V_{SW} = -1.4 \text{ V to } +1.4 \text{ V}$	0		0.8		Ω
R <sub>FLAT(ON)</sub>	On Resistance Flatness <sup>(2)</sup>	$I_{SW} = \pm 24 \text{ mA},$ $V_{SW} = -1.4 \text{ V to } +1.4 \text{ V}$	0		0.01		Ω
Icc	Quiescent Supply Current	SEL0 = SEL1 = V <sub>CC</sub>	3	0	50	70	μΑ
V <sub>IH</sub>	Input Voltage High (Select Pins)(3)		3	0.8•V <sub>CC</sub>			V
V <sub>IL</sub>	Input Voltage Low (Select Pins)(3)		3			0.2•V <sub>CC</sub>	V
I <sub>IN</sub>	Input Leakage Current (Select Pins)		3	0		±1	μΑ

#### Notes:

- 2. Guaranteed by test and characterization.
- 3. Voltages on select control pins must be  $\leq V_{CC}$ .

#### **AC Electrical Characteristics**

Typical values at  $T_A = 25$ °C unless otherwise specified.

Symbol	Parameter	Condition	V <sub>cc</sub> (V)	Тур.	Unit
t <sub>ON</sub>	Turn-On Time V <sub>CC</sub> to Output <sup>(4,5)</sup>	$R_L = 32 \Omega$ , $C_L = 10 pF$ , $V_{SW} = 1.4 V$	1.6	120	ns
t <sub>OFF</sub>	Turn-Off Time V <sub>CC</sub> to Output <sup>(4,5)</sup>	$R_L = 32 \Omega$ , $C_L = 10 pF$ , $V_{SW} = 1.4 V$	1.6	160	μs
O <sub>IRR</sub>	Off Isolation <sup>(4,5)</sup>	$R_L = 32 \Omega$ , $f = 20 \text{ kHz}$ , $V_{SW} = 0.35 V_{RMS}$	1.6	-90	dB
X <sub>TALK</sub>	Crosstalk <sup>(4,5)</sup>	$R_L = 32 \Omega$ , $f = 20 \text{ kHz}$ , $V_{SW} = 1 V_{RMS}$	0	-90	dB
BW	-3dB Bandwidth <sup>(5)</sup>	$R_L = 50 \Omega$ , $C_L = 0 pF$	0	<50	MHz
THD+N	Total Harmonic Distortion + Noise <sup>(4,5)</sup>	$R_L = 32 \Omega$ , $f = 20 Hz$ to 20 kHz, $V_{SW} = 1 V_{RMS}$	0	0.002	%

#### Notes:

- 4. SEL0=SEL1=LOW.
- 5. Guaranteed by characterization.

## Capacitance

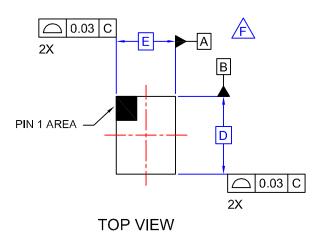
 $T_A = 25$ °C unless otherwise noted.

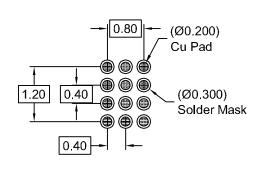
Symbol	Parameter	Condition	Тур.	Unit
Con	On Capacitance (Switch Conducting)	$V_{CC} = 0 \text{ V, f} = 1 \text{ MHz, } 400 \text{ mV}_{PP}$	10	pF
C <sub>OFF</sub>	Off Capacitance (Switch Isolated)	$V_{CC} = 1.6 \text{ V}, f = 1 \text{ MHz}, 400 \text{ mV}_{PP}$	10	рΓ

## **Product-Specific Dimensions**

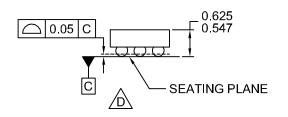
E D		X	Υ
1.16 mm	1.56 mm	0.18 mm	0.18 mm

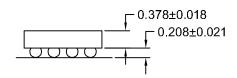
		REVISIONS		
1	REV	DESCRIPTION	DATE	APP'D / SITE
	1	Initial drawing release.	8-19-09	L. England / FSME



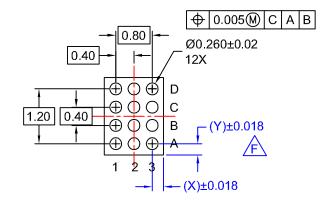


# RECOMMENDED LAND PATTERN (NSMD PAD TYPE)





#### SIDE VIEWS



**BOTTOM VIEW** 

### NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- E. PACKAGE NOMINAL HEIGHT IS 586 MICRONS ±39 MICRONS (547-625 MICRONS).
- F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.
- G. DRAWING FILENAME: MKT-UC012ACrev1.

APPROVALS	DATE	FAIR				
L. England	8-19-09	SEMICO				
DFTG. CHK. S. Martin	8-19-09	4.0	D A L L	\\		
ENGR. CHK.		12BALL WLCSP, 3X4 ARRAY				
		0.4MM PITCH, 250UM BALL				
PROJECTIO	٧	SCALE	SIZE	DRAWING NUMBER		REV
		N/A N/A MKT-UC012AC			1	
INCH [MM]	DO NO	SCALE	DRAWING	SHEET 1 of	1	

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